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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/662,107	09/12/2003	David H. Hwang	42P16017	9100	
7590 04/22/2005			EXAMINER		
Michael A. Be		GABOR, OTILIA			
Seventh Floor	KOLOFF, TAYLOR & Z	ART UNIT	PAPER NUMBER		
12400 Wilshire		2878			
Los Angeles, C	CA 90025	DATE MAILED: 04/22/2005			

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	on No.	Applicant(s)			
Office Action Summary		10/662,10	77	HWANG, DAVID H.			
		Examiner		Art Unit			
		Otilia Gab	or	2878			
Period fo	The MAILING DATE of this communication or Reply	appears on the	cover sheet with the c	orrespondence addr	ess		
THE - Exte after - If the - If NO - Failt Any	ORTENED STATUTORY PERIOD FOR REI MAILING DATE OF THIS COMMUNICATION Insions of time may be available under the provisions of 37 CFR SIX (6) MONTHS from the mailing date of this communication. It is period for reply specified above is less than thirty (30) days, a period for reply is specified above, the maximum statutory perior to reply within the set or extended period for reply will, by start reply received by the Office later than three months after the may be departed term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no ever reply within the state od will apply and wi tute, cause the app	ent, however, may a reply be tin story minimum of thirty (30) day Il expire SIX (6) MONTHS from ication to become ABANDONE	nely filed s will be considered timely. the mailing date of this comr D (35 U.S.C. § 133).	nunication.		
Status							
1)[🛛	Responsive to communication(s) filed on 12	September 2	2003.				
• —	This action is FINAL . 2b)⊠ This action is non-final.						
/—	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
-,	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposit	ion of Claims						
4)⊠	Claim(s) <u>1-27</u> is/are pending in the application.						
_	4a) Of the above claim(s) is/are withdrawn from consideration.						
•	5) Claim(s) is/are allowed.						
•	Claim(s) <u>1-27</u> is/are rejected.						
-	7) Claim(s) is/are objected to.						
8)	Claim(s) are subject to restriction and	d/or election r	equirement.				
Applicat	ion Papers						
, —	The specification is objected to by the Exam		_				
10)⊠ The drawing(s) filed on <u>12 September 2003</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.							
	Applicant may not request that any objection to t						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)∐	The oath or declaration is objected to by the	Examiner. No	ote the attached Office	Action or form PTO	-152.		
Priority	under 35 U.S.C. § 119						
-	Acknowledgment is made of a claim for fore All b) Some * c) None of: 1. Certified copies of the priority documents)-(d) or (f).			
	2. Certified copies of the priority documents			ion No			
	3. Copies of the certified copies of the profits				tage		
	application from the International Bur				90		
* ;	See the attached detailed Office action for a	•		ed.			
			·				
Attachmer	nt(s)						
	ce of References Cited (PTO-892)		4) Interview Summary				
	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB	/08)	Paper No(s)/Mail D 5) Notice of Informal F		52)		
	er No(s)/Mail Date	,	6) Other:	, , ,	•		

DETAILED ACTION

Specification

1. The disclosure is objected to because of the following informalities: the title includes a spelling error "diffration" should be --diffraction—.

Appropriate correction is required.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1, 5, 7, 9, 12, 13, 21-25, 27 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Purvis, Jr. et al. (U. S. Patent 5,540,494).

Purvis discloses a system and method for determining critical characteristics, such as the size, of a feature, the system comprising: a stage (manifold) to hold the subject structure (sample) that includes a feature (particle) with a size (radius) to be measured; a radiation source (laser) to emit radiation directed at the feature; a detector (photodiode, PMT) to detect a diffraction pattern caused by the radiation interacting with the feature and to generate a signal representative of at least in part of the diffraction pattern; and a computer coupled to the detector to receive the signal and to compare a feature size identifier of the diffraction pattern with a library of feature size identifiers, each feature size identifier in the library being associated with a known feature size

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(see Figs.1, 2, 3, 5, 7, 25-28, Col.4, line 60-Col.7, line 65, Col.45, line55-Col.47, line 20). In operation, the subject having a feature (particle) is irradiated with light from the laser light source to form a diffraction pattern; the diffraction pattern is detected using a detector; and the particle size (radius) is determined based on a comparison between the measured size (which is done through measuring the diffraction pattern intensity) and the reference sizes saved in the library of the computer (see Figs.25-28).

Regarding claims 5, 7 Purvis discloses that his method works when the light is reflected and/or transmitted by the sample and thus the detection is inherently positioned on the same and/or opposite side from the feature depending on what type of measurement (reflected or transmitted) is being done.

Regarding claims 9, 23, 24, 25 Purvis discloses that the feature size identifier is an envelope plot whereby the positions of the diffraction minimas and maximas are plotted and detected using the detector (see Figs.2).

Regarding claim 13 Purvis discloses that the radiation source is a laser (see Fig.1).

Regarding claim 27 Purvis discloses that the feature size (particle radius) is calculated.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the

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invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

5. Claims 6, 8, 11, 17, 18, 19, 20, 26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Purvis and further in view of Littau et al. (U. S. Patent 6,429,930).

Purvis discloses a general method of determining the size of a feature using its diffraction pattern, however it fails to disclose that the feature comprises a transmissive window defined by a radiation-opaque microelectronic structure mask substrate and that there is a vacuum enclosure surrounding the source, the stage and the detector. However, these features are inherently present in a system where the feature, the size of which is to be determined, is a microelectronic structure. This is clearly shown by Littau, which discloses a system and method for determining the characteristics of a microelectronic structure using the diffraction signature difference analysis. Since the diffraction signature analysis method is applicable to many different features, it would have been obvious to one having ordinary skill in the art at the time the invention was made to utilize the Purvis method on the feature of Littau, and therefore, using the Purvis method on a feature that has a window defined by a radiation-opaque microelectronic structure mask substrate where the source, detector and the stage are enclosed in vacuum. Regarding claim 26 Littau discloses a feature that has a known pitch. Regarding claims 11, 17, 19 Littau discloses that high -energy beam and/or X-rays can be used as radiation sources besides the disclosed laser source.

6. Claims 2, 3, 4, 10, 14-16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Purvis.

Purvis fails to disclose that the laser source is a helium-neon source emitting

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radiation having a wavelength of about 633 nanometers and that the detector is a charge-coupled-device, however since he does not put a limitation as to the type of laser sources and detectors that can be used, and since he discloses using a radiation of wavelength 618 nanometers, it would have been obvious to use the claimed light source and detector, since CCD's and helium-neon lasers are well known and conventionally used in this field, and thus it would have been obvious to one having ordinary skill in the art to substitute one for the other. Regarding claim 2 Purvis fails to disclose using a radiation with a wavelength that is longer than the feature size, however, since he discloses that the type of radiation is not limited but can be chosen according to its suitability for the intended measurement, it would have been obvious to one having ordinary skill in the art at the time the invention was made to use a radiation with a wavelength that is longer than the feature size since it has been held that choosing the right value of an effective variable involves only routine skill in the art (*In re Boesch*, 617 F.2d 272, 205 USPQ 215 (CCPA 1980)).

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Takemura et al. (5,374,989); Giglio (4,755,052); Cantrall et al. (5,530,551).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Otilia Gabor whose telephone number is 571-272-2435.

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The examiner can normally be reached on Monday, Thursday-Friday between 9am-5pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Porta can be reached on 571-272-2444. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

> Otilia Gabor Examiner Art Unit 2878

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